

Supplementary information

Ultrathin Circular Polarimeter Based on Chiral Plasmonic Metasurface and Monolayer MoSe₂

Qiao Jiang, Bowen Du, Meiling Jiang, Donglin Liu, Zhixin Liu, Bowen Li, Zheng Liu, Xing Zhu and Zheyu Fang*

School of Physics, State Key Lab for Mesoscopic Physics, Academy for Advanced Interdisciplinary Studies, and Collaborative Innovation Center of Quantum Matter, Peking University, Beijing 100871, China.

*Email: zhyfang@pku.edu.cn

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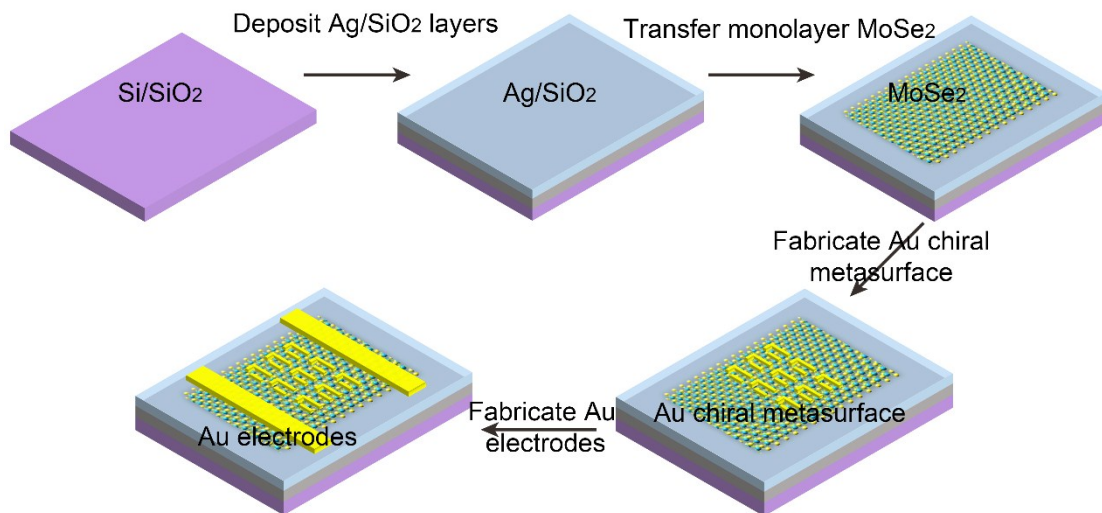


Fig. S1. Schematic flowchart illustrating the fabrication process for the ultrathin circular polarimeter.

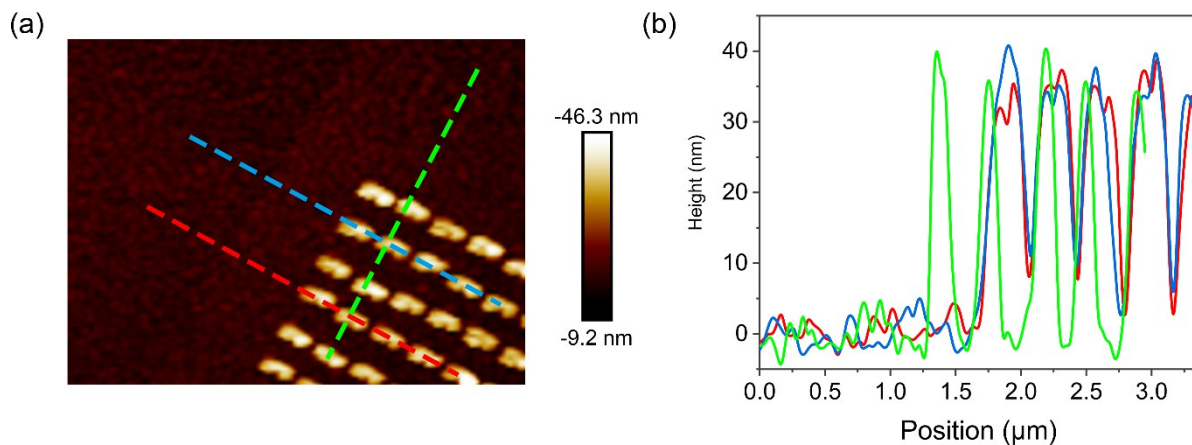


Fig. S2. (a) AFM topographic image of a test sample fabricated with the same process as main text. (b) The height along the corresponding dashed lines in the AFM topographic image. A thickness of 40 nm can be obtained from these measurements.

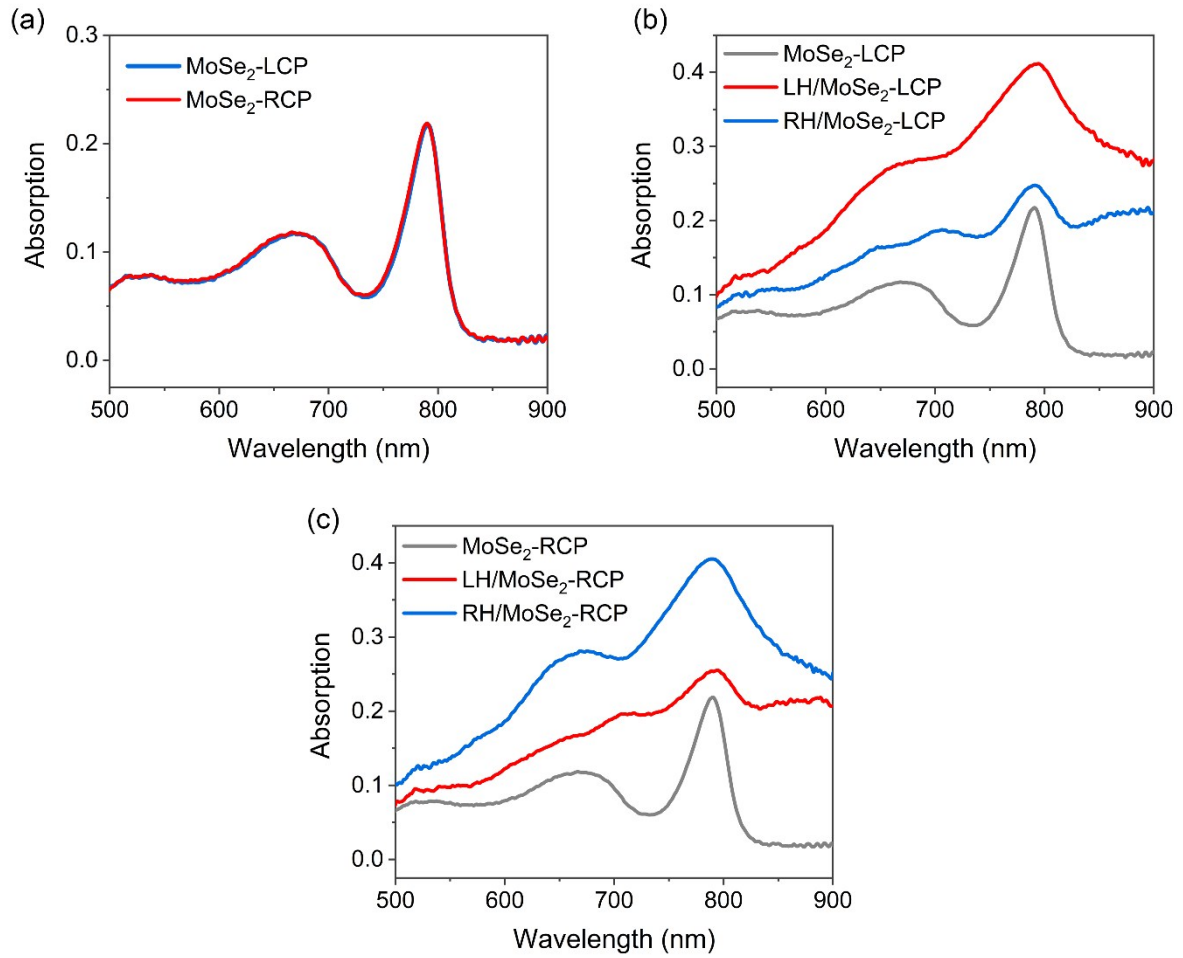


Fig. S3. (a) Measured absorption spectra of MoSe₂ without chiral metasurfaces under LCP and RCP light incidence. (b, c) Measured absorption spectra of bare MoSe₂ (without chiral metasurfaces), MoSe₂ integrated with left-handed metasurface and MoSe₂ integrated with right-handed metasurface under LCP (b) and RCP (c) incidence.

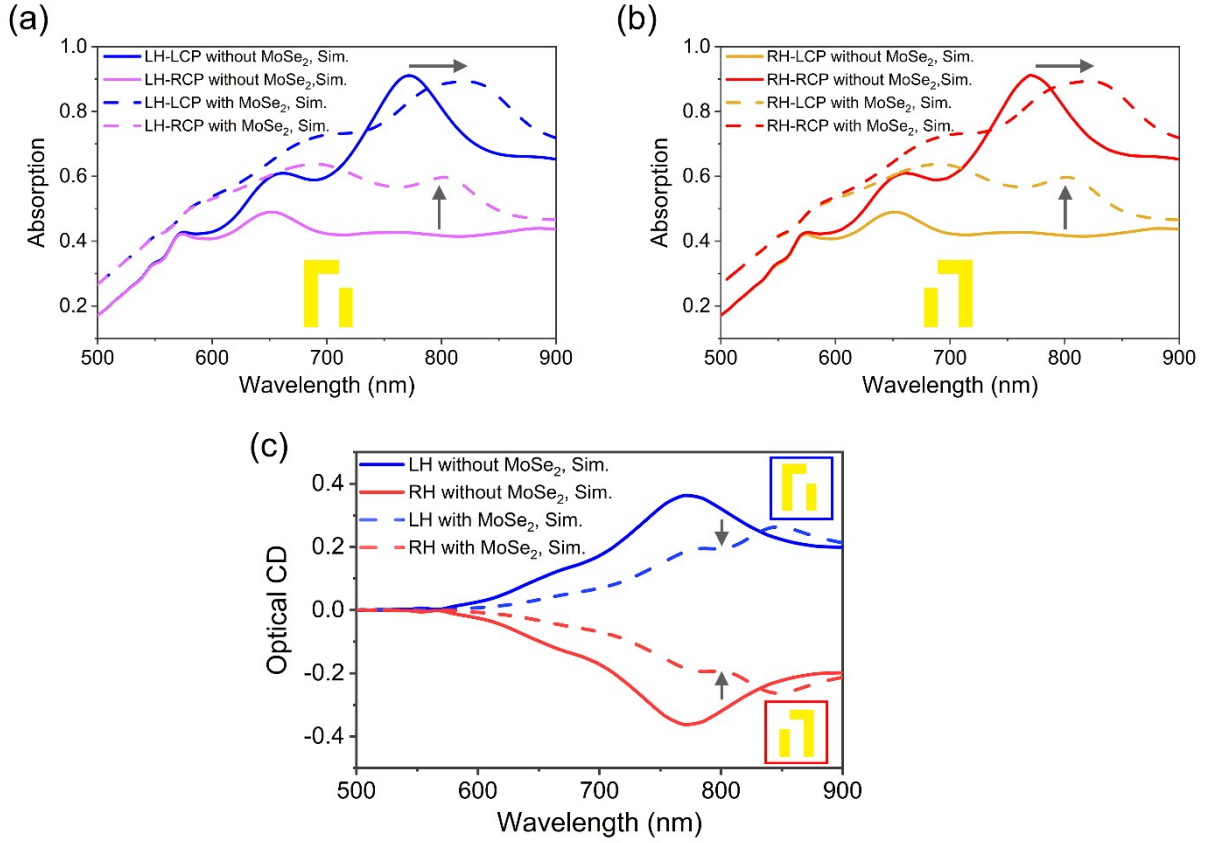


Fig. S4. Simulated absorptions and optical CD spectra of left-handed and right-handed plasmonic metasurfaces with and without MoSe₂ monolayer under CP light incidence. (a) Simulated absorptions of left-handed metasurface with (solid lines) and without (dashed lines) MoSe₂ monolayer. (b) Simulated absorptions of right-handed metasurface with (solid lines) and without (dashed lines) MoSe₂ monolayer. (c) Simulated optical CD spectra of left-handed (blue lines) and right-handed (red lines) plasmonic metasurfaces. The absorptions increase and are red-shifted slightly because of the influence of MoSe₂, and this further leads to the red-shift and decrease of optical CD as shown in (c).

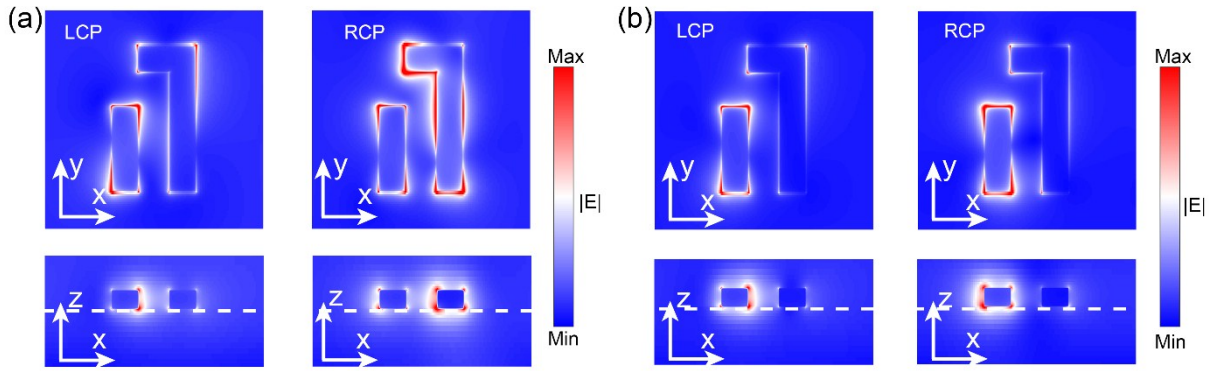


Fig. S5. Simulated electric field distributions of right-handed metasurface at wavelength of 790 nm (a) and 890nm (b) under CP light incidence.

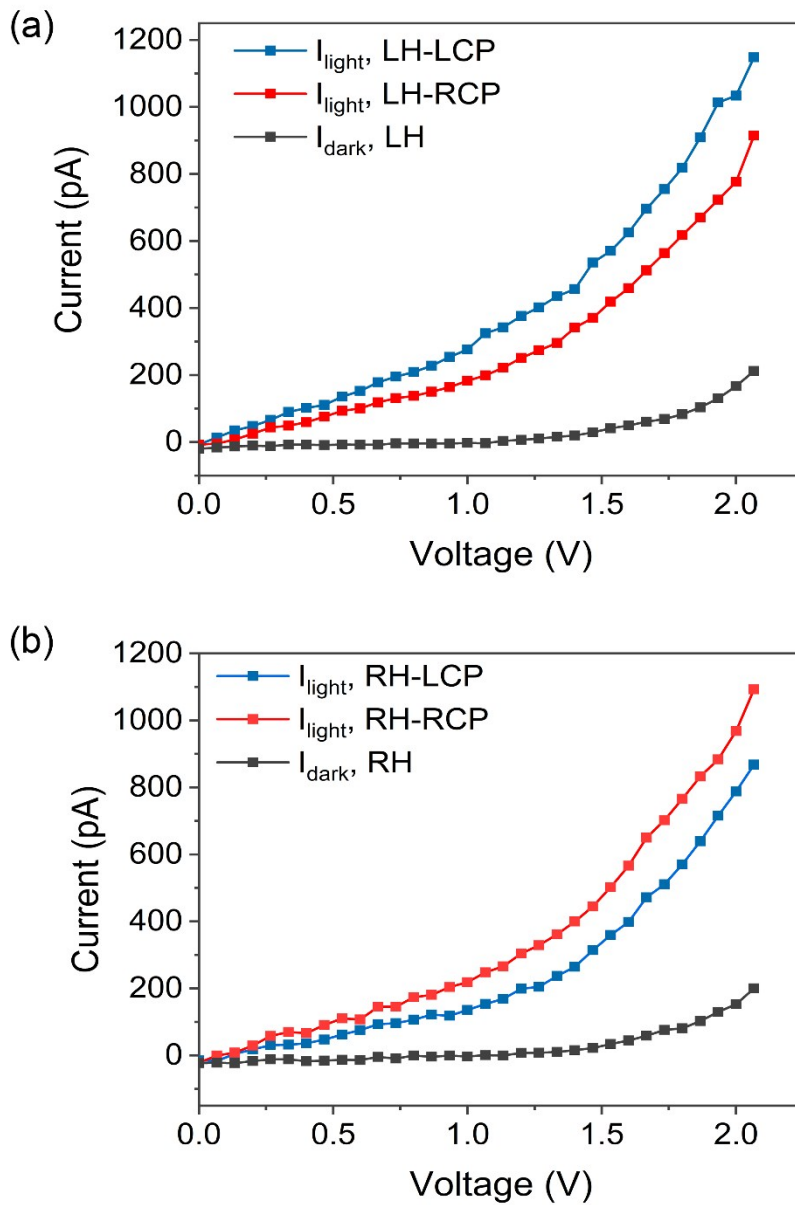


Fig. S6. Measured current with illumination (I_{light}) and without illumination (I_{dark}) of left-

handed (a) and right-handed (b) metasurfaces.

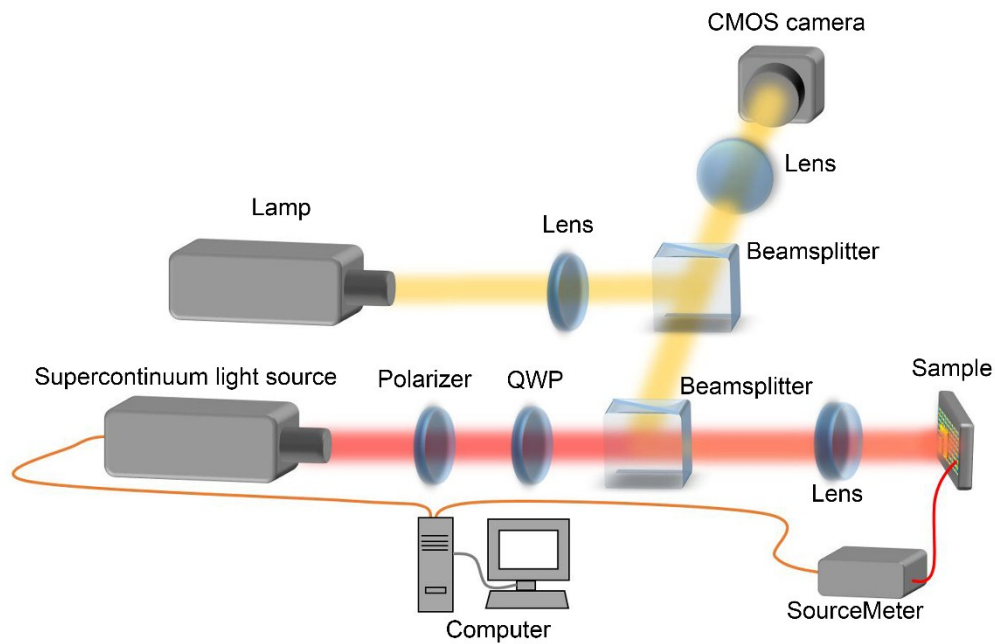


Fig. S7. Schematic of photocurrent detection system. A cascaded polarizer and quarter-wave plate (QWP) are used to generate circularly polarized incident light. The illumination system with a lamp and CMOS camera is used to find the fabricated devices on the substrate, which is turned off when measuring the photocurrent.